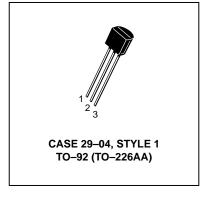
Switching Transistor PNP Silicon

COLLECTOR 3 2 BASE 1 EMITTER

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	VCEO	-12	Vdc	
Collector-Base Voltage	VCBO	-12	Vdc	
Emitter-Base Voltage	VEBO	-4.0	Vdc	
Collector Current — Continuous	IC	-80	mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

MPS3640



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	R_{θ} JC	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage ($I_C = -100 \mu Adc$, $V_{BE} = 0$)	V(BR)CES	-12	_	Vdc
Collector-Emitter Sustaining Voltage ⁽¹⁾ (I _C = -10 mAdc, I _B = 0)	VCEO(sus)	-12	_	Vdc
Collector–Base Breakdown Voltage (I _C = –100 μAdc, I _E = 0)	V(BR)CBO	-12	_	Vdc
Emitter-Base Breakdown Voltage (I _E = -100 μAdc, I _C = 0)	V(BR)EBO	-4.0	_	Vdc
Collector Cutoff Current $(V_{CE} = -6.0 \text{ Vdc}, V_{BE} = 0)$ $(V_{CE} = -6.0 \text{ Vdc}, V_{BE} = 0, T_{A} = 65^{\circ}\text{C})$	ICES		-0.01 -1.0	μAdc
Base Current $(V_{CE} = -6.0 \text{ Vdc}, V_{EB} = 0)$	lΒ	_	-10	nAdc

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic			Min	Max	Unit
ON CHARACTERIS	TICS(1)	•		•	
DC Current Gain ($I_C = -10 \text{ mAdc}$, $V_{CE} = -0.3 \text{ Vdc}$) ($I_C = -50 \text{ mAdc}$, $V_{CE} = -1.0 \text{ Vdc}$)		hFE	30 20	120 —	_
Collector-Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}$, $I_B = -1.0 \text{ mAdc}$) ($I_C = -50 \text{ mAdc}$, $I_B = -5.0 \text{ mAdc}$) ($I_C = -10 \text{ mAdc}$, $I_B = -1.0 \text{ mAdc}$, $I_A = 65^{\circ}\text{C}$)		VCE(sat)	_ _ _ _	-0.2 -0.6 -0.25	Vdc
Base-Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -0.5$ mAdc) ($I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc)		VBE(sat)	-0.75 -0.75 	-0.95 -1.0 -1.5	Vdc
SMALL-SIGNAL C	HARACTERISTICS				
Current-Gain — Bandwidth Product ($I_C = -10 \text{ mAdc}$, $V_{CE} = -5.0 \text{ Vdc}$, $f = 100 \text{ MHz}$)		fΤ	500	_	MHz
Output Capacitance (V _{CB} = -5.0 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	_	3.5	pF
Input Capacitance (VEB = -0.5 Vdc, I _C = 0, f = 1.0 MHz)		C _{ibo}	_	3.5	pF
SWITCHING CHAR	ACTERISTICS			•	
Delay Time	$(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, V_{BE(off)} = -1.9 \text{ Vdc},$	t _d	_	10	ns
Rise Time	$I_{B1} = -5.0 \text{ mAdc}$	t _r	_	30	ns
Storage Time	$(V_{CC} = -6.0 \text{ Vdc}, I_C = -50 \text{ mAdc}, I_{B1} = I_{B2} = -5.0 \text{ mAdc})$	t _S	_	20	ns
Fall Time	1	t _f	_	12	ns
Turn–On Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = -5.0 \text{ mAdc})$ $(V_{CC} = -1.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = -0.5 \text{ mAdc})$		ton	_ _	25 60	ns
Turn–Off Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = I_{B2} = -5.0 \text{ mAdc})$ $(V_{CC} = -1.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = I_{B2} = -0.5 \text{ mAdc})$		^t off	_ _	35 75	ns

^{1.} Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

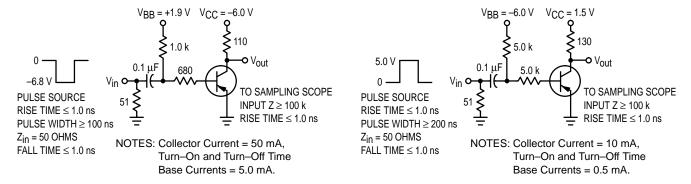


Figure 1. Figure 2.

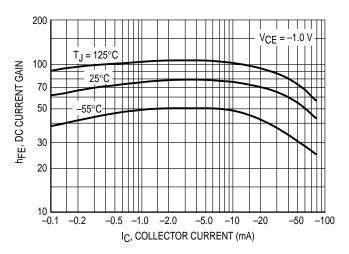


Figure 3. DC Current Gain

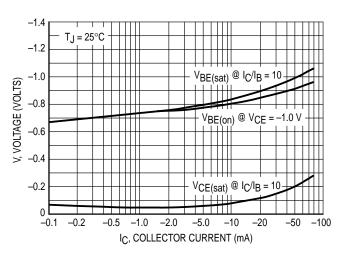


Figure 4. "On" Voltages

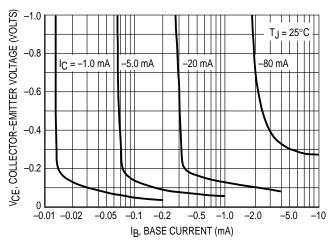


Figure 5. Collector Saturation Region

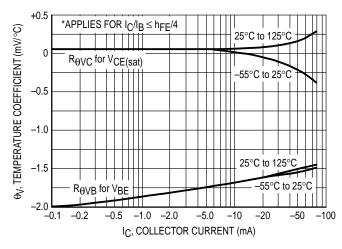


Figure 6. Temperature Coefficients

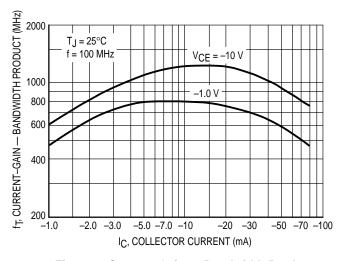


Figure 7. Current-Gain — Bandwidth Product

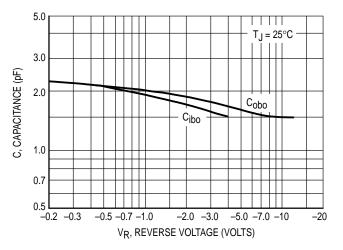
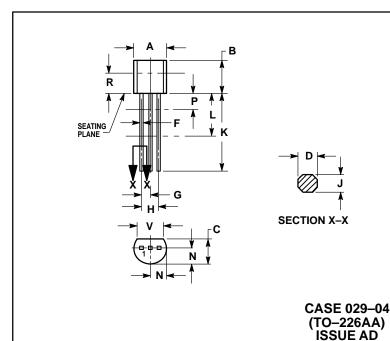


Figure 8. Capacitance

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
7	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3 43	

STYLE 1: PIN 1. EMITTER BASE

3. COLLECTOR

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (M) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us:

USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki, 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298



